

Phonon-Driven Pathway to the 1T-TaS₂ Hidden State

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Among the layered transition-metal dichalcogenides, 1T-TaS₂ uniquely exhibits a hidden, metallic charge density wave phase. A myriad of experiments have demonstrated the ability to use an optical or electrical excitation to access this metastable state [2,3], but ultimately the non-thermal mechanism that unlocks this hidden phase has eluded observations. Here we used time-resolved X-ray diffraction with three-dimensional reciprocal space resolution to reveal the coherently driven dynamics tied to both the commensurate and hidden charge density wave states. Supported by dynamic structure factor simulations [3] and unsupervised machine learning, our results show that an out-of-plane A_g phonon mode in the commensurate state facilitates a dismantling of dimers and a subsequent interlayer restacking to the hidden state. Furthermore, progressive bulk switching and a transient interlayer melting of the hidden phase underscores the significance that stacking dynamics play in an otherwise strongly correlated two-dimensional material.

[1] L. Stojchevska, I. Vaskivskiy, T. Mertelj, P. Kusar, D. Svetin, S. Brazovskii, and D. Mihailovic, Ultrafast switching to a stable hidden quantum state in an electronic crystal, *Science* **344**, 177 (2014).

[2] C. Burri, N. Hua, D. F. Sanchez, W. Hu, H.G. Bell, R. Venturini, S.-W. Huang, A.G. McConnell, F. Dizdarević, A. Mraz, D. Svetin, B. Lipovšek, M. Topič, D. Kazazis, G. Aeppli, D. Grolimund, Y. Ekinci, D. Mihailović, and S. Gerber, Imaging of electrically controlled van der Waals layer stacking in 1T-TaS₂, *Nat. Commun.* **16**, 10296 (2025).

[3] N. Hua, F. Petocchi, H. G. Bell, G. Aeppli, P. Werner, and S. Gerber, Interlayer stacking controls the electronic properties of the van der waals material 1T-TaS₂, *Phys. Rev. Res.* **8**, L012047 (2026).